Preferred Device

# **Silicon Controlled Rectifiers**

## **Reverse Blocking Thyristors**

Designed primarily for half-wave ac control applications, such as motor controls, heating controls, and power supplies; or wherever half-wave, silicon gate-controlled devices are needed.

- Blocking Voltage to 800 Volts
- On-State Current Rating of 25 Amperes RMS
- High Surge Current Capability 300 Amperes
- Rugged, Economical TO–220AB Package
- Glass Passivated Junctions for Reliability and Uniformity
- Minimum and Maximum Values of I<sub>GT</sub>, V<sub>GT</sub>, and I<sub>H</sub> Specified for Ease of Design
- High Immunity to dv/dt 100 V/µsec Minimum @ 125°C
- Device Marking: Logo, Device Type, e.g., MCR25D, Date Code

#### **MAXIMUM RATINGS** (T<sub>J</sub> = $25^{\circ}$ C unless otherwise noted)

Symbol	Value	Unit
V <sub>DRM,</sub> V <sub>RRM</sub>	400 600 800	Volts
IT(RMS)	25	A
ITSM	300	A
l <sup>2</sup> t	373	A <sup>2</sup> sec
PGM	20.0	Watts
PG(AV)	0.5	Watt
IGM	2.0	A
Тј	-40 to +125	°C
T <sub>stg</sub>	-40 to +150	°C
	VDRM, VRRM IT(RMS) ITSM I <sup>2</sup> t PGM PG(AV) IGM TJ	VDRM, VRRM 400 600 800   IT(RMS) 25   ITSM 300   I <sup>2</sup> t 373   PGM 20.0   PG(AV) 0.5   IGM 2.0   TJ -40 to +125   Tstg -40 to

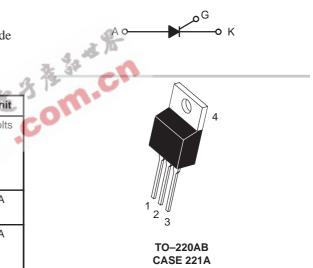
(1) V<sub>DRM</sub> and V<sub>RRM</sub> for all types can be applied on a continuous basis. Ratings apply for zero or negative gate voltage; positive gate voltage shall not be applied concurrent with negative potential on the anode. Blocking voltages shall not be tested with a constant current source such that the voltage ratings of the devices are exceeded.



### **ON Semiconductor**

http://onsemi.com

## SCRs 25 AMPERES RMS 400 thru 800 VOLTS



STYLE 3

PIN ASSIGNMENT			
1	Cathode		
2	Anode		
3	Gate		
4	Anode		

#### ORDERING INFORMATION

Device	Package	Shipping	
MCR25D	TO220AB	50 Units/Rail	
MCR25M	TO220AB	50 Units/Rail	
MCR25N	TO220AB	50 Units/Rail	

**Preferred** devices are recommended choices for future use and best overall value.

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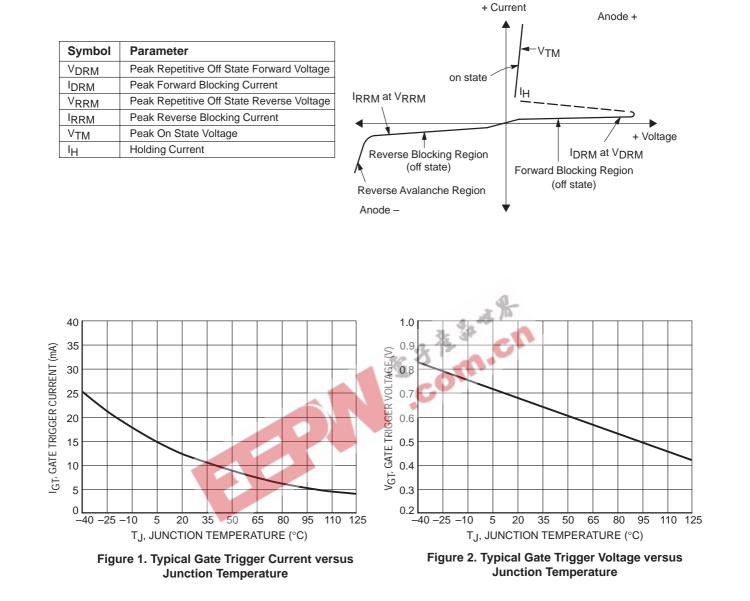
### THERMAL CHARACTERISTICS

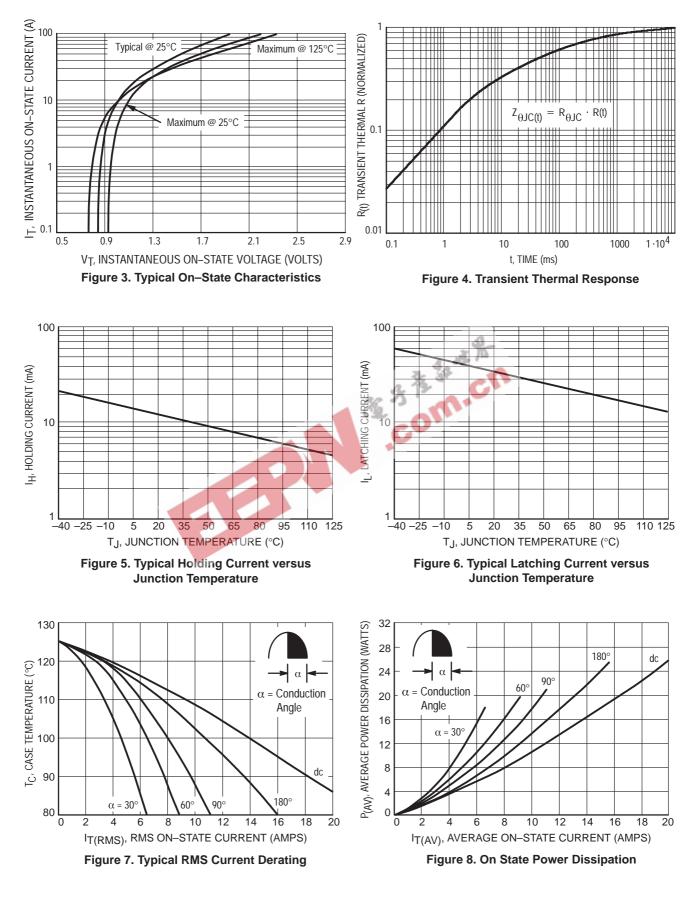
Characteristic	Symbol	Value	Unit
Thermal Resistance — Junction to Case — Junction to Ambient	R <sub>θJC</sub> R <sub>θJA</sub>	1.5 62.5	°C/W
Maximum Lead Temperature for Soldering Purposes 1/8" from Case for 10 Seconds	ТL	260	°C

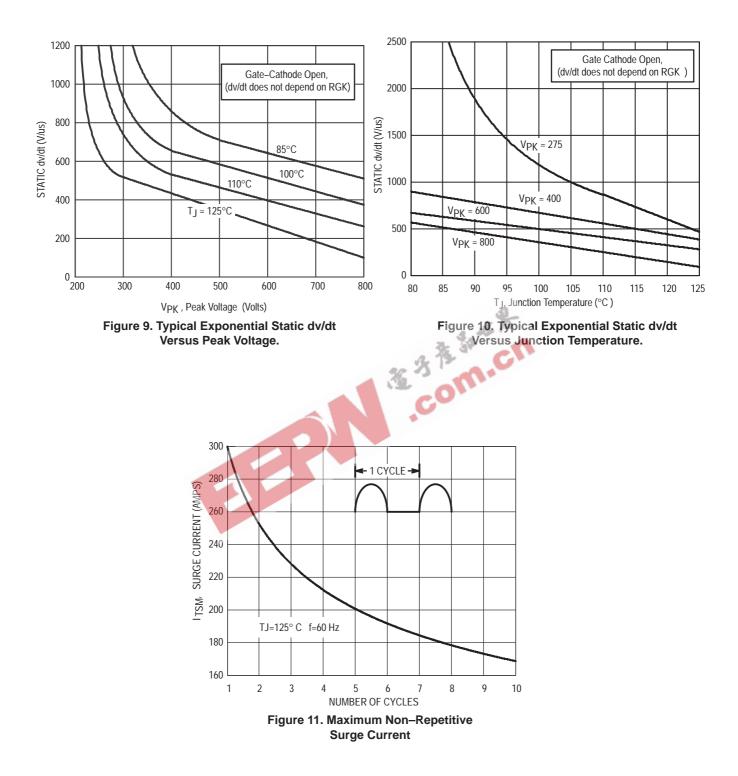
#### **ELECTRICAL CHARACTERISTICS** (T<sub>J</sub> = $25^{\circ}$ C unless otherwise noted)

Characteristic	Symbol	Min	Тур	Max	Unit
OFF CHARACTERISTICS	•				
$ \begin{array}{l} \mbox{Peak Repetitive Forward or Reverse Blocking Current} \\ (V_{AK} = Rated \ V_{DRM} \ or \ V_{RRM}, \ Gate \ Open) \\ T_J = 25^{\circ}C \\ T_J = 125^{\circ}C \end{array} $	I <sub>DRM</sub> I <sub>RRM</sub>			0.01 2.0	mA
ON CHARACTERISTICS					
Peak Forward On-State Voltage* ( $I_{TM}$ = 50 A)	VTM	—	—	1.8	Volts
Gate Trigger Current (Continuous dc) (V_D = 12 V, R_L = 100 $\Omega$ )	IGT	4.0	12	30	mA
Gate Trigger Voltage (Continuous dc) (V_D = 12 V, R_L = 100 $\Omega$ )	VGT	0.5	0.67	1.0	Volts
Holding Current (V <sub>D</sub> =12 Vdc, Initiating Current = 200 mA, Gate Open)	Ιн	5.0	13	40	mA
Latching Current ( $V_D$ = 12 V, $I_G$ = 30 mA)	١L	3 15	35	80	mA
DYNAMIC CHARACTERISTICS	3. 3	2			
Critical Rate of Rise of Off–State Voltage ( $V_D = 67\%$ of Rated $V_{DRM}$ , Exponential Waveform, Gate Open, $T_J = 125^{\circ}C$ )	d∨/dt	100	250	-	V/µs
Critical Rate of Rise of On–State Current (IPK = 50 A, Pw = 30 µsec, diG/dt = 1 A/µsec, Igt = 50 mA)	di/dt	-	_	50	A/μs
Indicates Pulse Test: Pulse Width ≤ 2.0 ms, Duty Cycle ≤ 2%.					

#### Voltage Current Characteristic of SCR

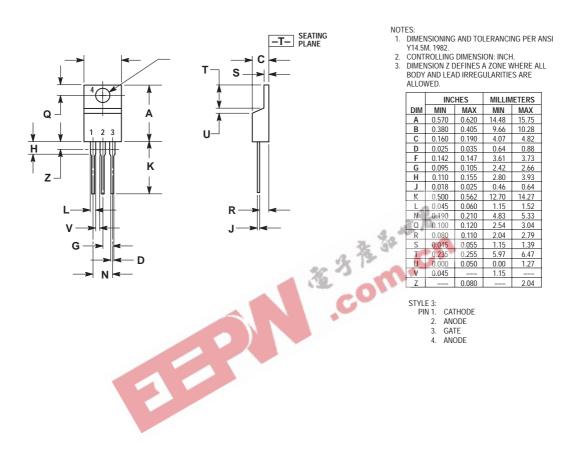






#### PACKAGE DIMENSIONS

TO-220AB CASE 221A-09 ISSUE Z



## <u>Notes</u>



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